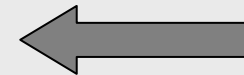

Peak Current Performances from Microscopic Tips Paul Scherrer Institut

Low Emittance Gun Project

Goals :

- Electron Beam Emittance $< 5 \cdot 10^{-8}$ m.rad
- Capable of driving an X-FEL Linac (Peak Current / Stability / ...)

	Goals
Minimum Peak Current (A)	5
Normalized Slice Emittance (m.rad)	$5 \cdot 10^{-8}$
Pulse Duration, full width (ps)	40
Repetition rate (Hz)	10
Gun Energy (MeV)	4



<http://leg.web.psi.ch/>

Low Emittance Gun Project

1. Electron Source

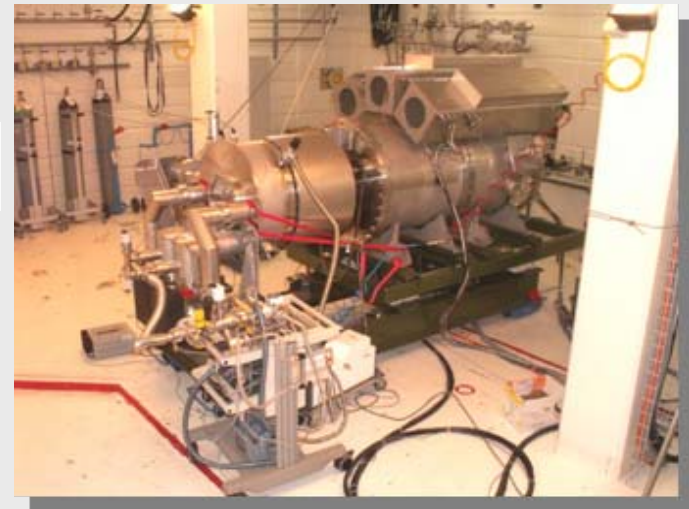
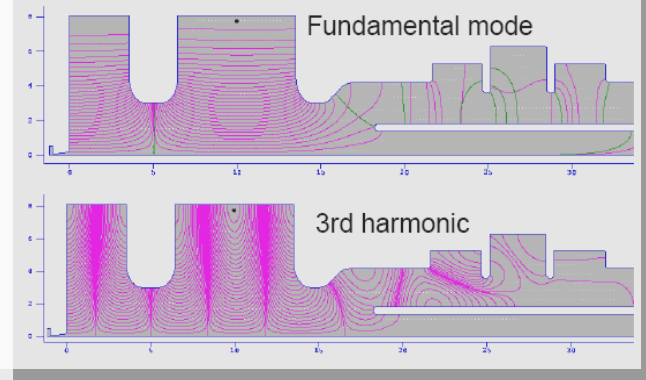
- Field Emitter Arrays
- Single Tip
- Laser Assisted

2. Diode Acceleration

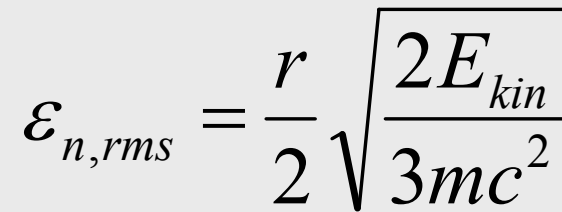
- Gap : 4mm
- Pulser: 500 kV; 250ns
- High Gradient: 250 MV/m

3. RF Acceleration

- Two frequency Cavity Design
- 1.5 GHz + 4.5 GHz
- Flat Top wave



Ultimate limit in Accelerators: Intrinsic emittance of the Electron Source

$$\varepsilon_{n,rms} = \frac{r}{2} \sqrt{\frac{2E_{kin}}{3mc^2}}$$
The equation is centered on the slide. Two arrows originate from the equation: one points from the variable 'r' to the text 'Size of the produced Electron Beam', and the other points from the square root term to the text 'Thermal Agitation (r.m.s transverse momentum) of emitted electrons'.

Size of the produced
Electron Beam

Thermal Agitation
(r.m.s transverse momentum)
of emitted electrons

Field Emission: High Current Density (10^{12}A/m^2)

Energy Spread ($4kT < 0.3\text{eV}$)

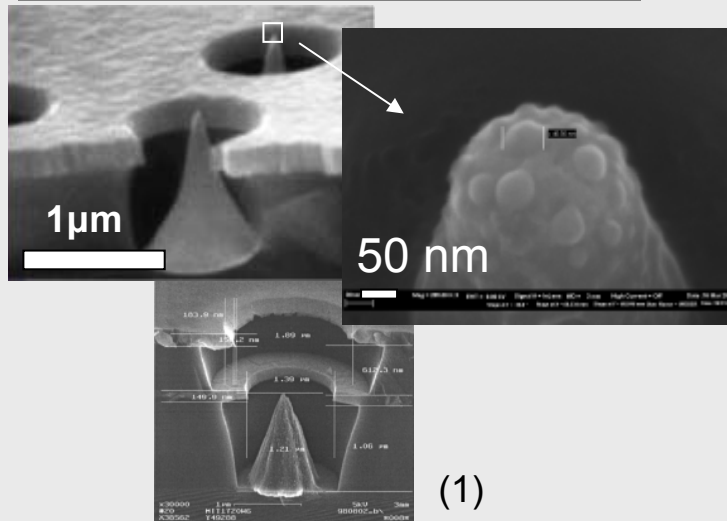
*Uniform Beam over r
+ Maxwell Distribution*

Field Emission requires High Field: $F_{\text{Surface}} > 3 \text{ GV} / \text{m}$



Field Enhancement with **Tip Effect**

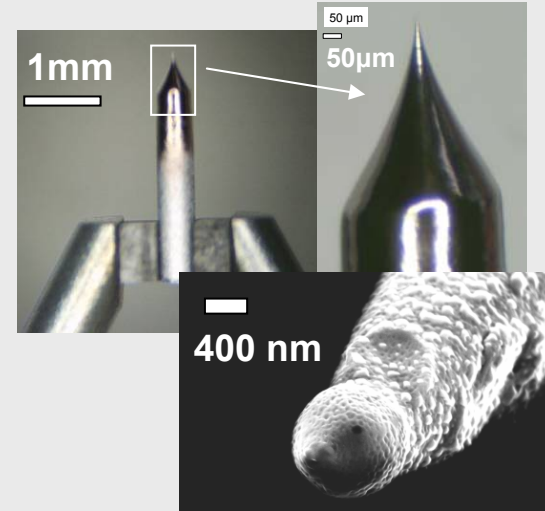
Field Emitter Arrays (FEAs)



(1)

Microelectronic Techniques

Single Tip



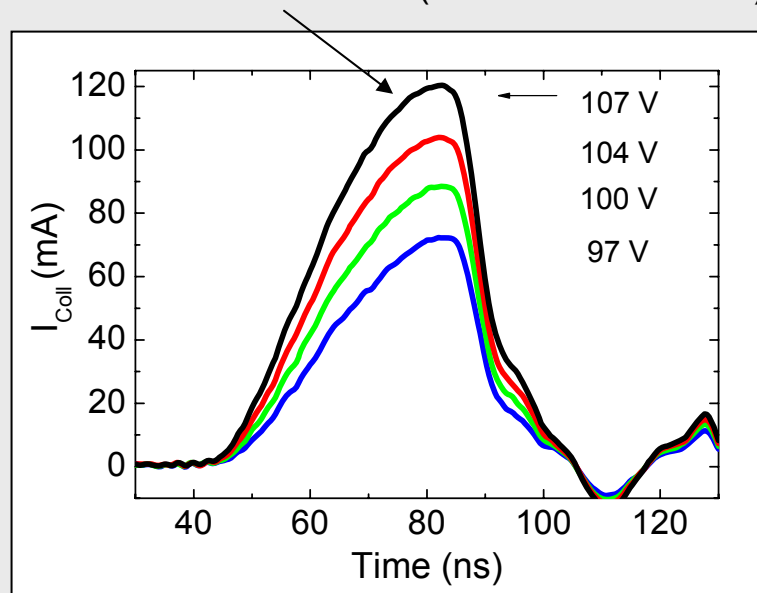
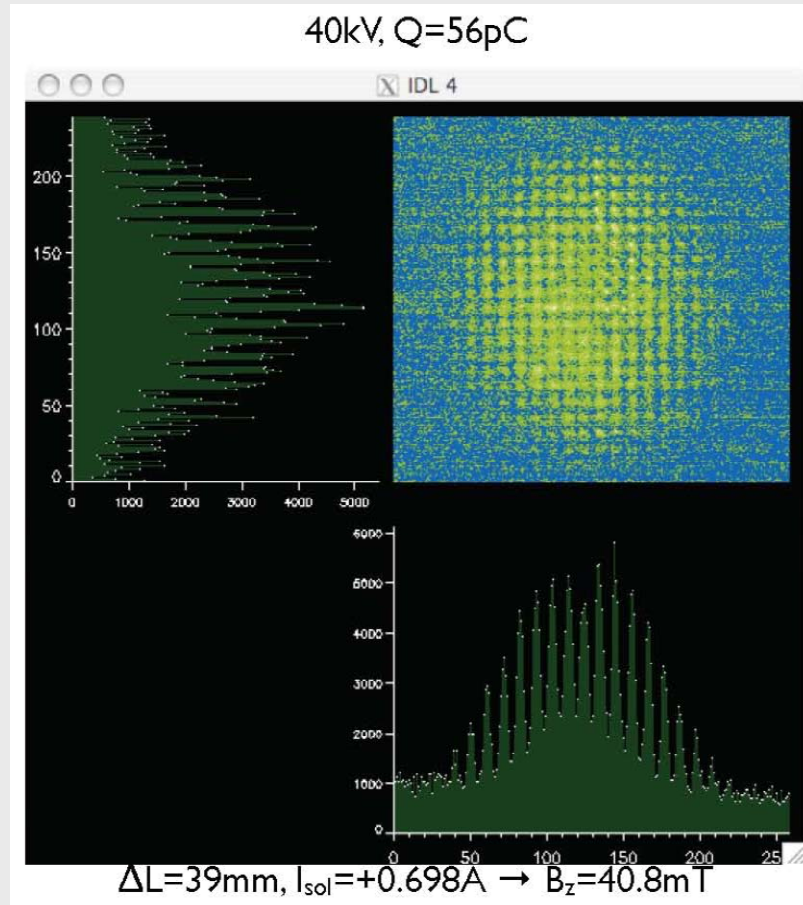
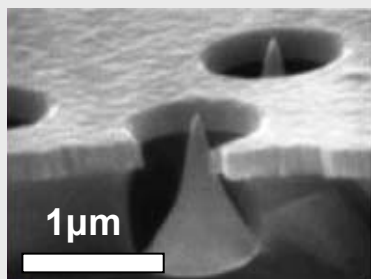
Etched Wire (**ZrC**; HfC; ...)

Field Emitter Array (FEA)

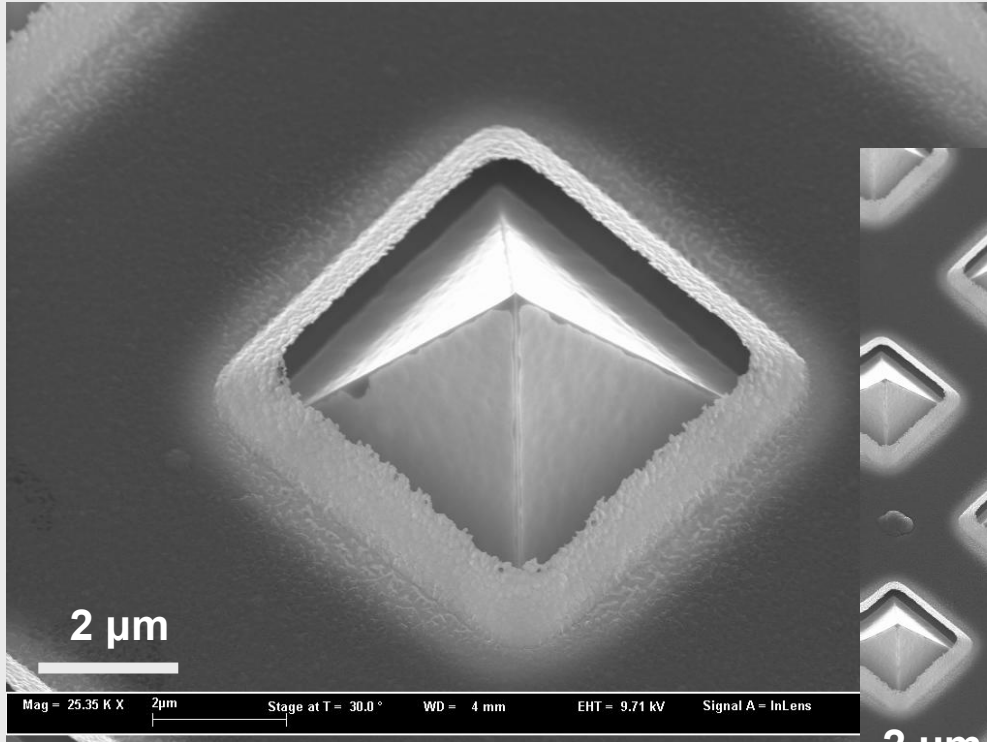
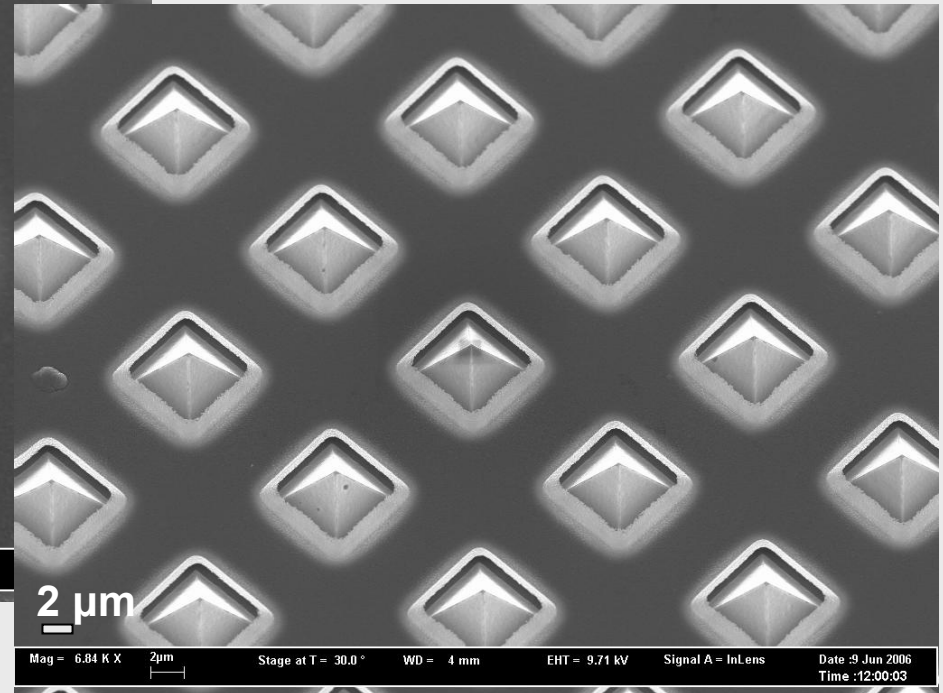
Tests on Commercial Field Emitter Arrays

120 mA (Pulses of 30ns at 10HZ)

(Commercial Device)

50000 Tips
 $\varnothing = 1 \text{ mm}$ 

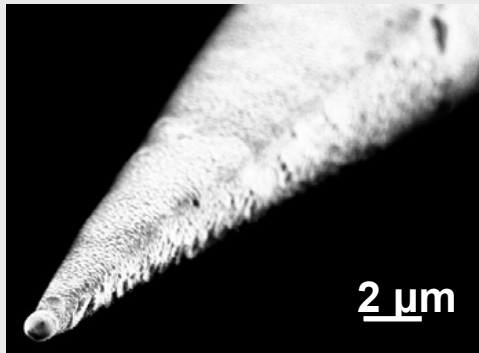
Projected Emittance **Single Gated FEA:**
 $\epsilon_n \sim 2.10^{-6} \text{ m.rad at } 40 \text{ keV}$

**Pyramid Shape**

- Mo Tips (Field Enhancement Factor: $\langle \beta \rangle \sim 90$)
- Metallic wafer

Single Tip

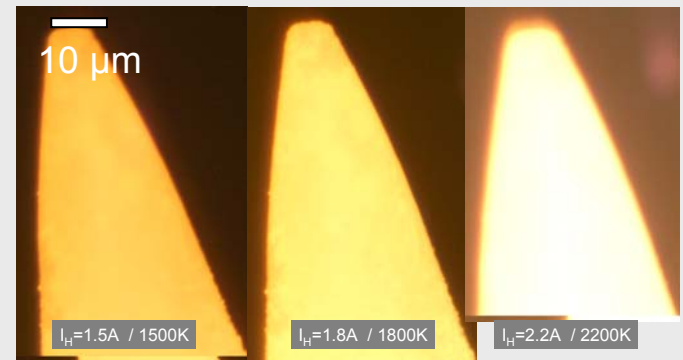
Single Tip Electron Source



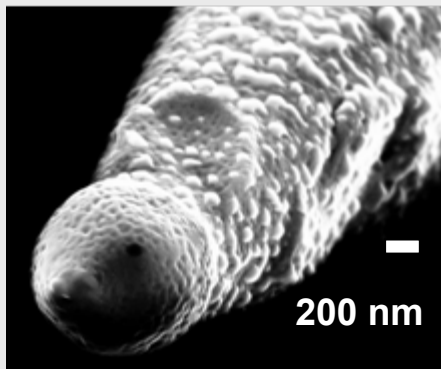
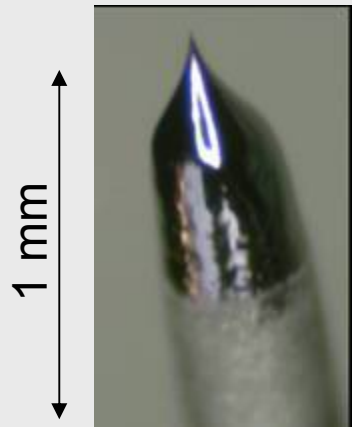
⇒ ZrC robust, $\Phi_{\text{ZrC}} \sim 3.5 \text{ eV}$

⇒ Possibility of Faceting the Tip

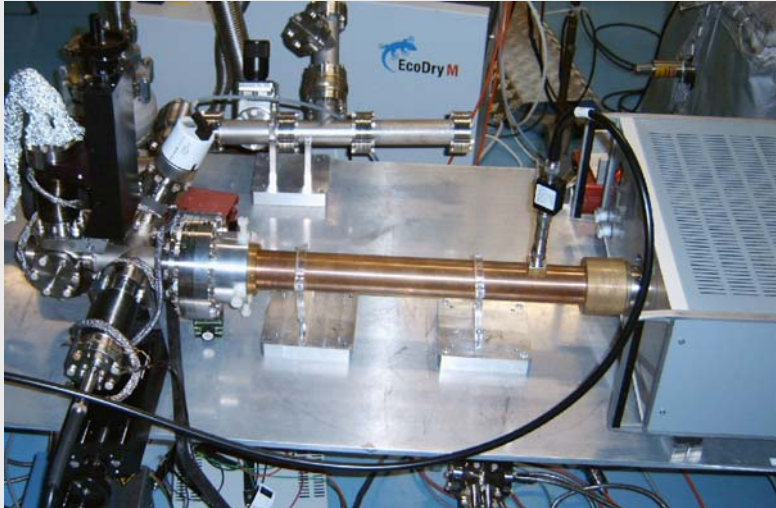
$r_{\text{apex}} \sim 1 \text{ to } 5 \mu\text{m}$



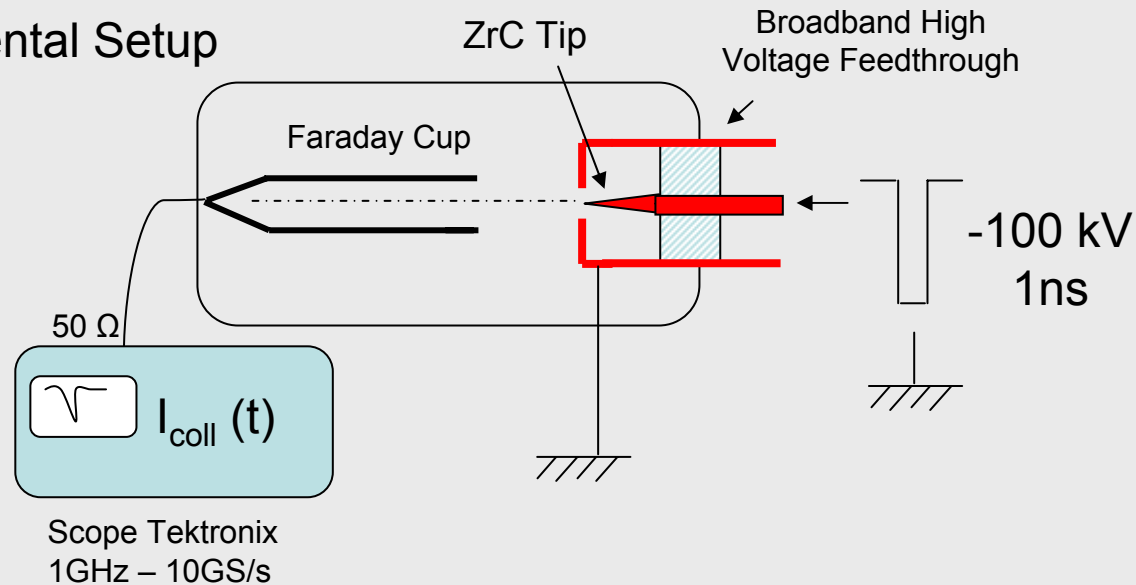
⇒ Required Operating Voltage
 $V_{\text{Tip}} > 10 \text{ kV}$



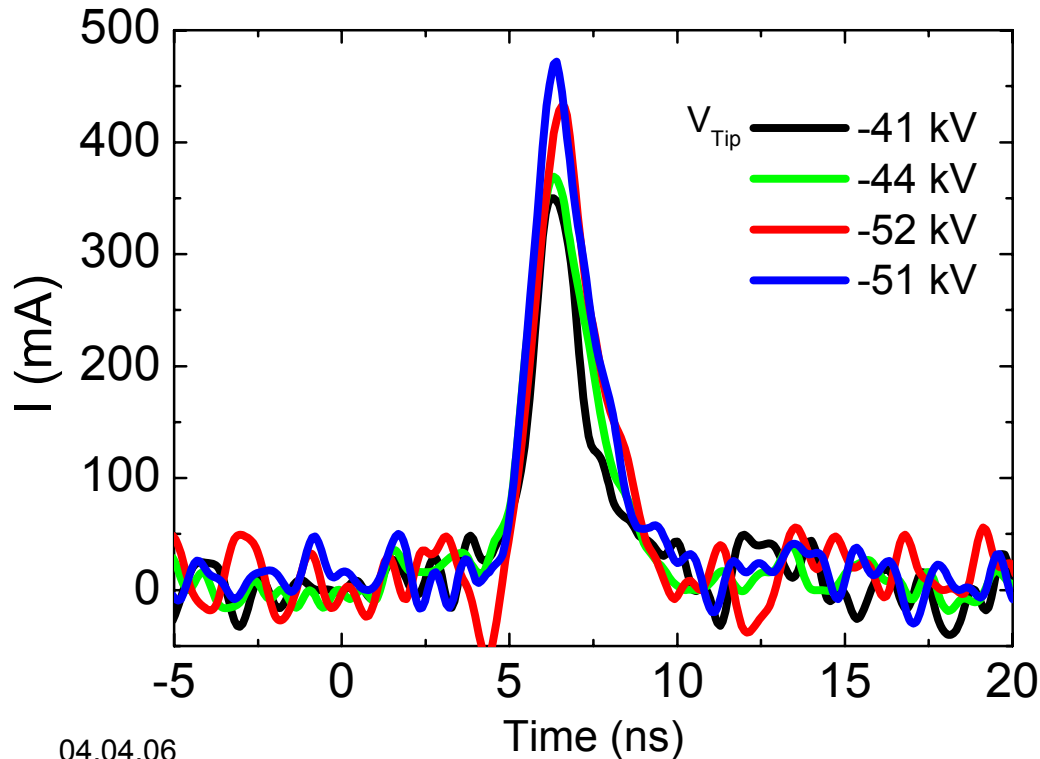
Single Tip ZrC performances



Experimental Setup



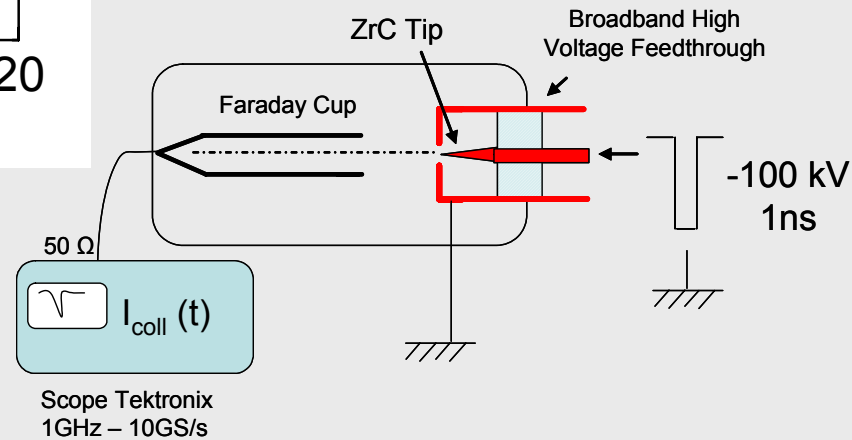
High Current Pulses from a ZrC Tip



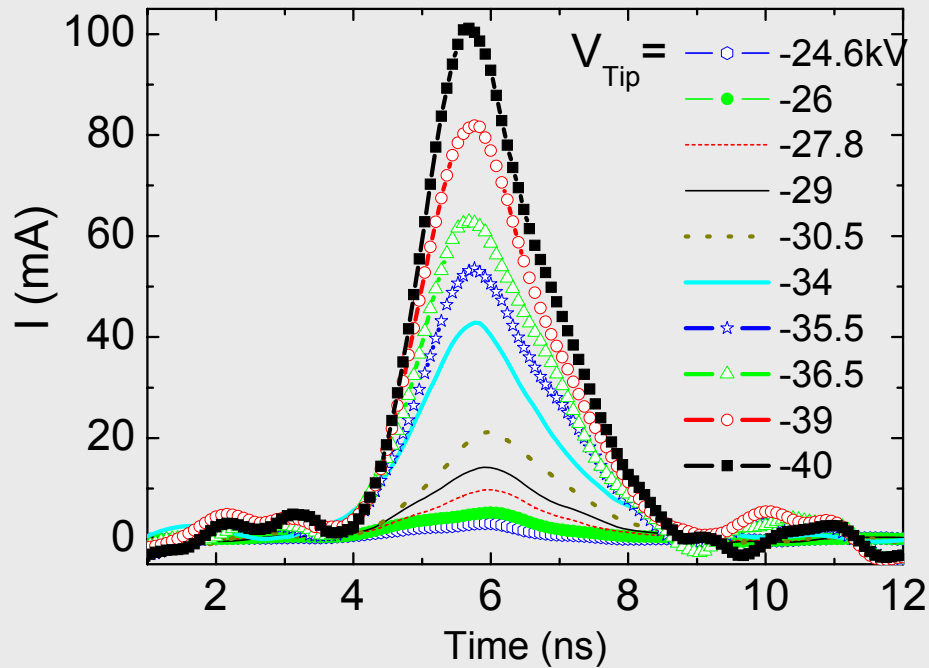
04.04.06

ZrC Tip
 10^{-9} Torr

Peak Current
 as high as **470 mA**



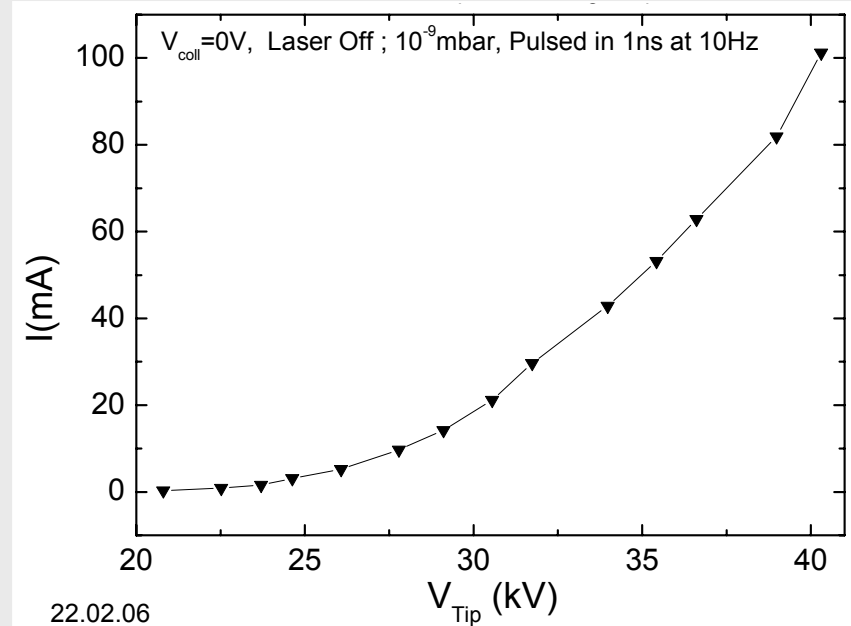
Field Emitted Current – Voltage Characteristic



Fowler – Nordheim Dependence



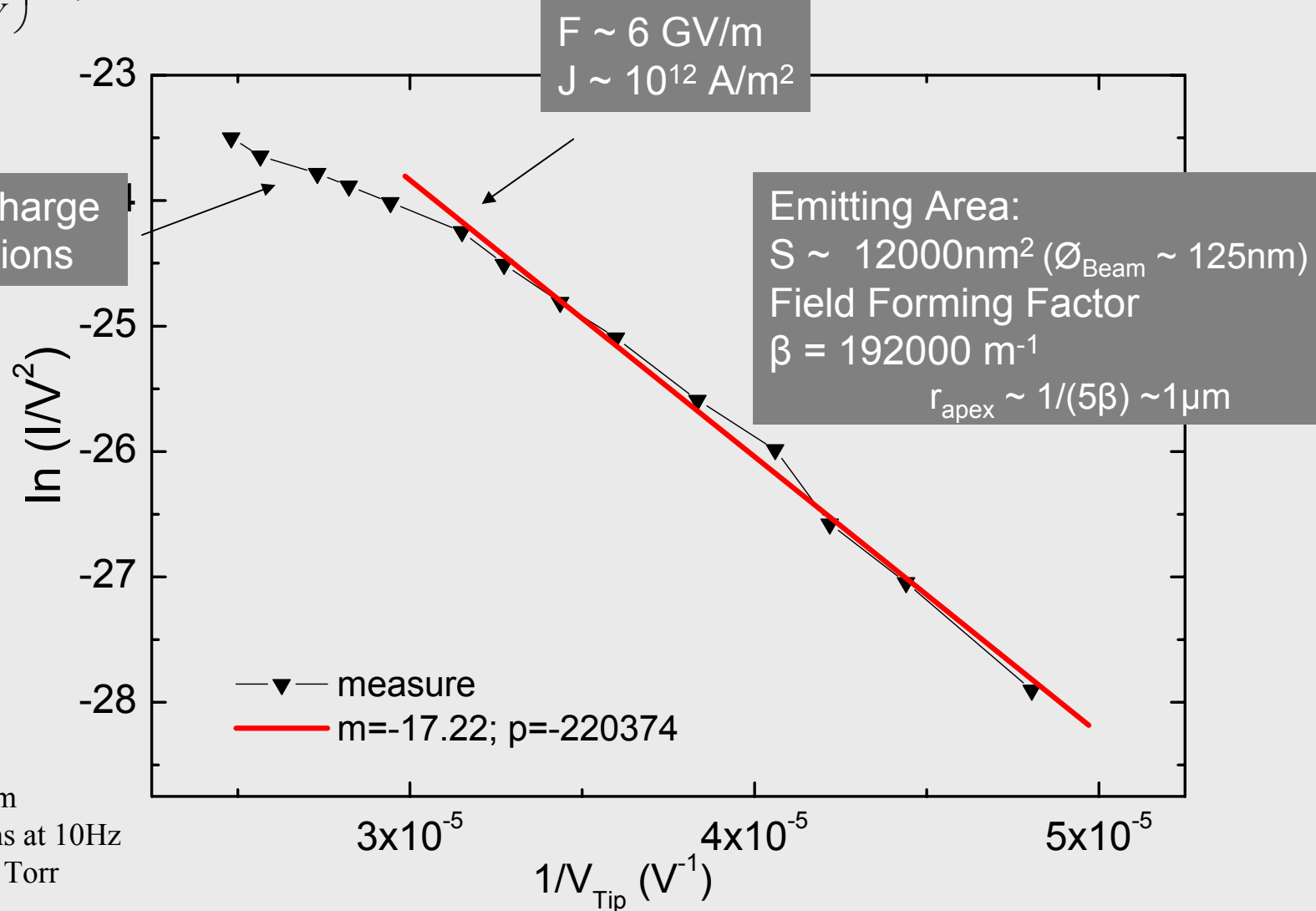
Field Emission Regime



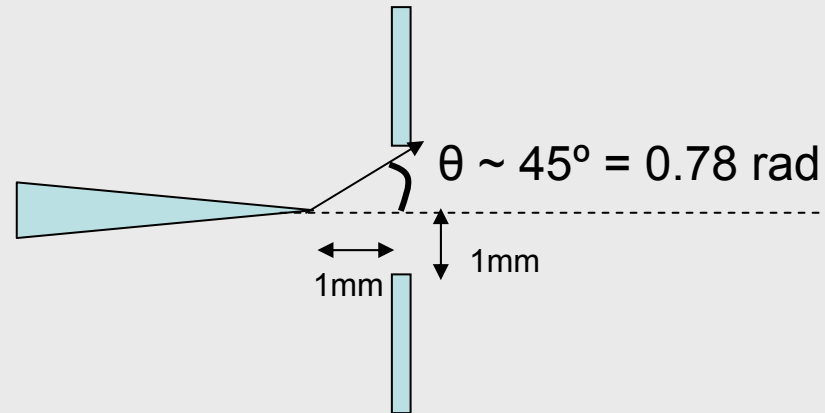
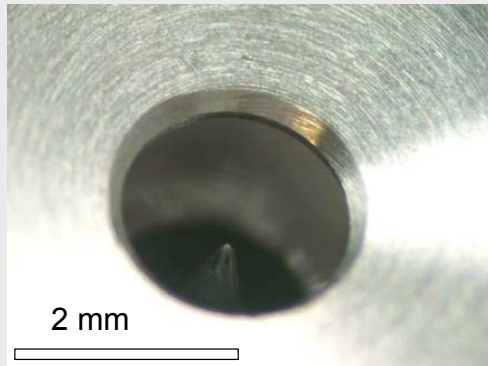
ZrC Tip, Gate $\phi \sim 2\text{mm}$
 Voltage Pulses: 1ns at 10Hz
 $\Phi_{\text{ZrC}} \sim 3.5\text{eV}$, 10^{-9}Torr

Fowler – Nordheim Analysis

$$\ln\left(\frac{I}{V^2}\right) = -p\left(\frac{1}{V}\right) + m$$



ZrC Tip, Gate 2mm
 Voltage Pulses: 1ns at 10Hz
 $\Phi_{\text{ZrC}} \sim 3.5 \text{ eV}$, 10^{-9} Torr

Measure 1

$$S \sim 12000 \text{ nm}^2$$

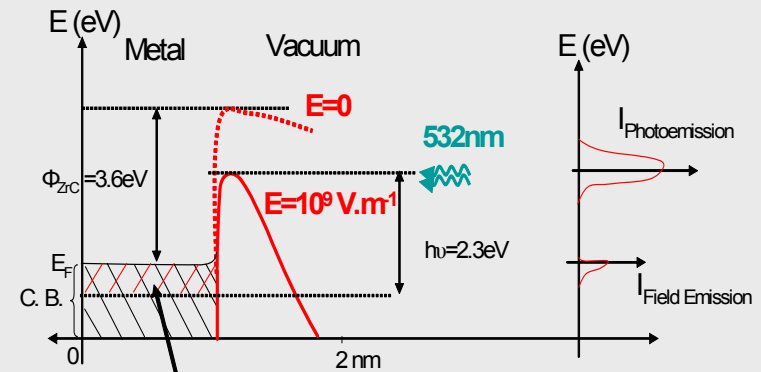
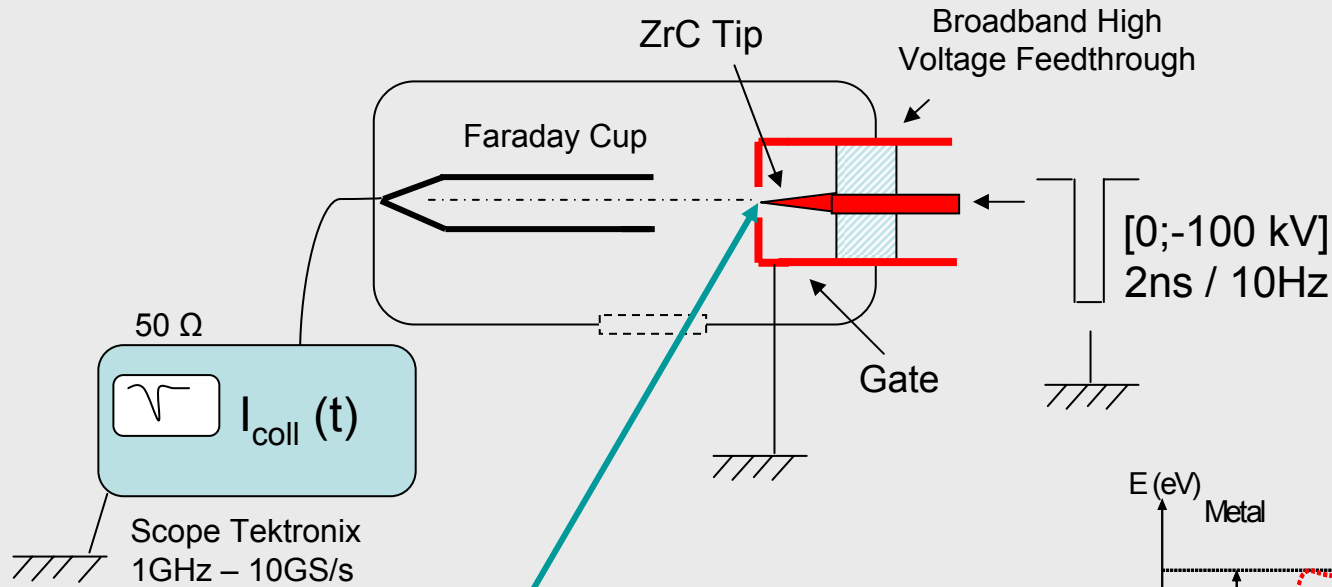
$$\varnothing_{\text{Beam}} \sim 125 \text{ nm}$$

$$\beta = 192000 \text{ m}^{-1}$$

$$r_{\text{apex}} \sim 1/(5\beta) \sim 1 \mu\text{m}$$

$$\varepsilon_n \sim r_{\text{beam}} \cdot \theta \sim 62 \text{ nm} \cdot 0.78 \text{ rad} \sim \mathbf{5 \cdot 10^{-8} \text{ m} \cdot \text{rad}}$$

$$B_{\text{Max}} = \frac{I_{\text{Max}}}{(2\pi)^2 \varepsilon_n^2} \sim 10^{12} \text{ A} \cdot \text{m}^{-2} \cdot \text{rad}^{-2}$$

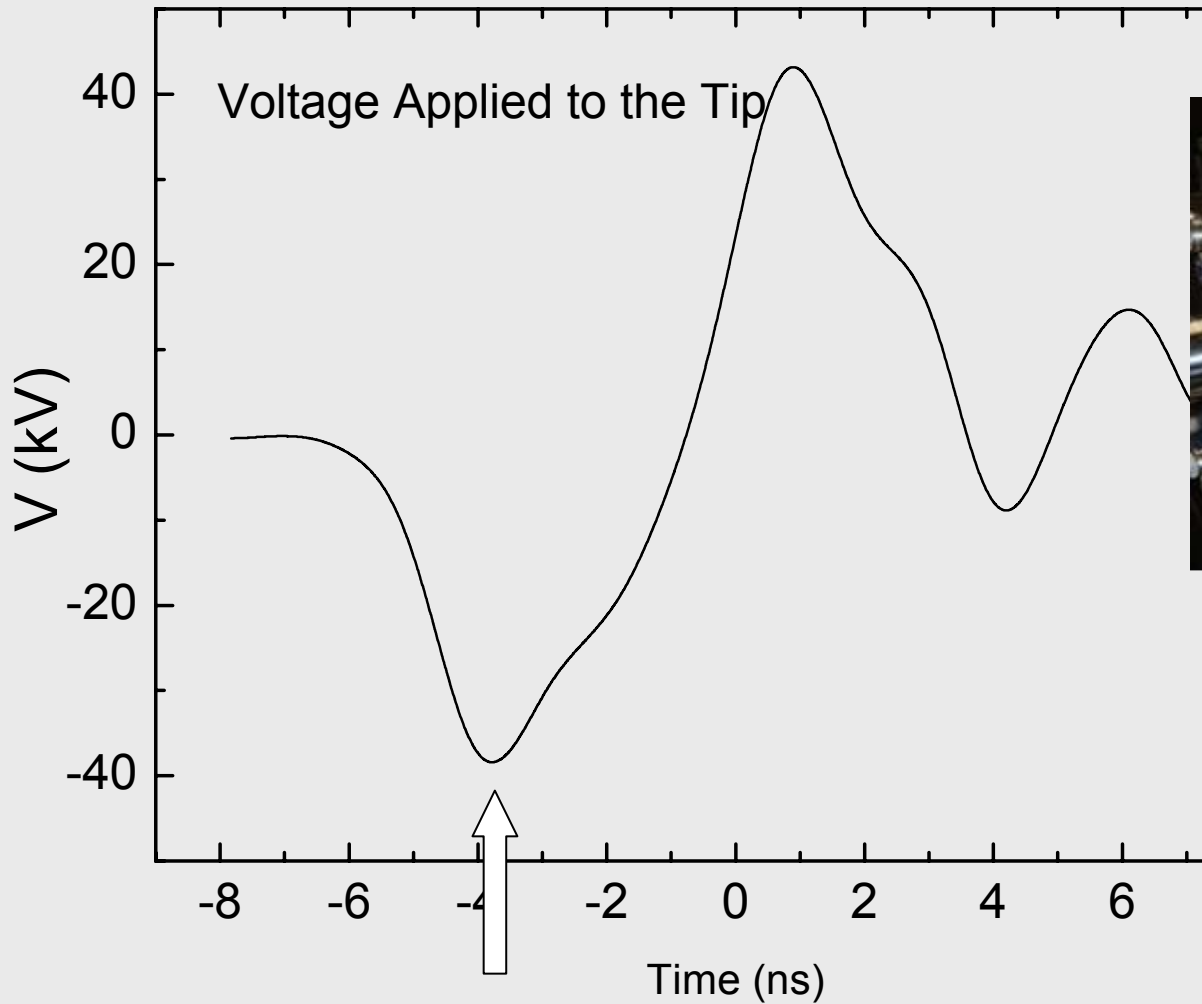


Energy range from where electrons can be directly photo-emitted !

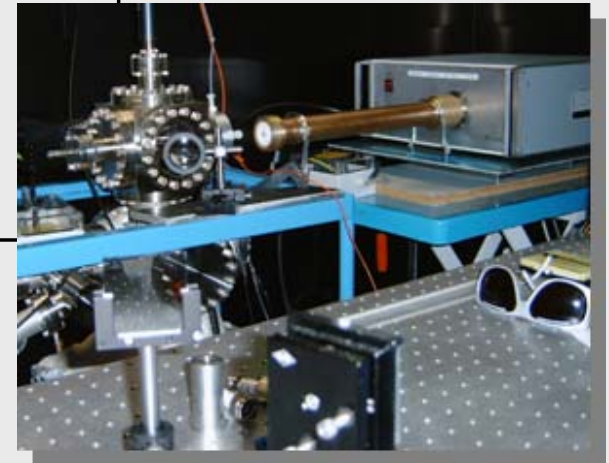
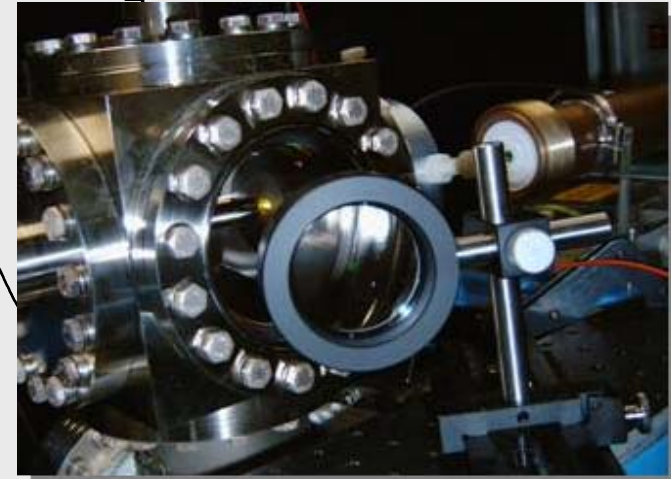
Picoseconds Laser Pulses
 $< 40 \mu\text{J}$; 30ps Full Width;
 10 Hz; 532nm



* Ref: C. H. Garcia *et al.*, Nucl. Instr. and Meth. A **483**, 273-276 (2002).



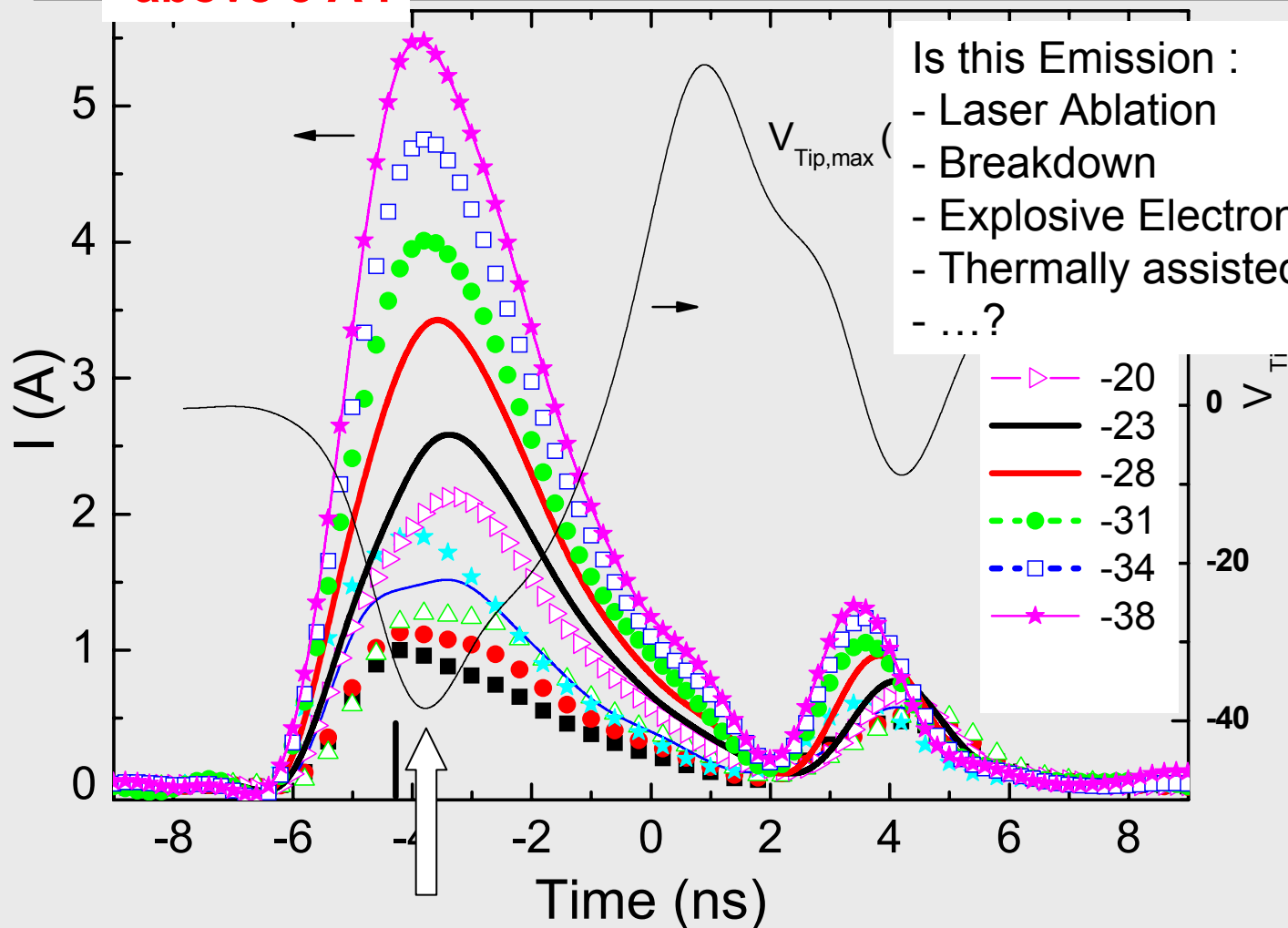
Laser Pulse: 532nm; 20μJ; 30ps; 10Hz;
 $P_{\text{Laser}} = 0.7 \text{ MW}; < 7 \cdot 10^9 \text{ W/cm}^2$





Electric Pulses + Laser Pulses

above 5 A !



Laser Pulse: 532nm; 20 μ J; 30ps; 10Hz;
 $P_{\text{Laser}} = 0.7$ MW; $< 7 \cdot 10^9$ W/cm²

FEA

- First tests of FEAs from PSI by Dec. 2006
- Laser Assisted FEAs

Single Tip

- Emittance Measurements
- Further tests of Laser Assisted Field Emission
- Implementation in 500kV Pulser